

# ADC124S021 4-Channel, 50 ksps to 200 ksps, 12-Bit A/D Converter

Check for Samples: ADC124S021

### **FEATURES**

- Specified Over a Range of Sample Rates.
- Four Input Channels
- Variable Power Management
- Single Power Supply with 2.7V 5.25V Range

#### **APPLICATIONS**

- Portable Systems
- Remote Data Acquisition
- Instrumentation and Control Systems

### **KEY SPECIFICATIONS**

DNL: +0.4 / -0.2 LSB (typ)
 INL: ± 0.35 LSB (typ)
 SNR: 72.0 dB (typ)

Power Consumption

3V Supply: 2.2 mW (typ)5V Supply: 7.9 mW (typ)

#### DESCRIPTION

The ADC124S021 is a low-power, four-channel CMOS 12-bit analog-to-digital converter with a high-speed serial interface. Unlike the conventional practice of specifying performance at a single sample rate only, the ADC124S021 is fully specified over a sample rate range of 50 ksps to 200 ksps. The converter is based on a successive-approximation register architecture with an internal track-and-hold circuit. It can be configured to accept up to four input signals at inputs IN1 through IN4.

The output serial data is straight binary, and is compatible with several standards, such as SPI™, QSPI™, MICROWIRE, and many common DSP serial interfaces.

The ADC124S021 operates with a single supply that can range from +2.7V to +5.25V. Normal power consumption using a +3V or +5V supply is 2.2 mW and 7.9 mW, respectively. The power-down feature reduces the power consumption to just 0.14  $\mu$ W using a +3V supply, or 0.32  $\mu$ W using a +5V supply.

The ADC124S021 is packaged in a 10-lead VSSOP package. Operation over the industrial temperature range of -40°C to +85°C is ensured.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Table 1. Pin-Compatible Alternatives by Resolution and Speed<sup>(1)</sup>

| Resolution | Specified for Sample Rate Range of: |                 |                    |  |  |  |
|------------|-------------------------------------|-----------------|--------------------|--|--|--|
|            | 50 to 200 ksps                      | 200 to 500 ksps | 500 ksps to 1 Msps |  |  |  |
| 12-bit     | ADC124S021                          | ADC124S051      | ADC124S101         |  |  |  |
| 10-bit     | ADC104S021                          | ADC104S051      | ADC104S101         |  |  |  |
| 8-bit      | ADC084S021                          | ADC084S051      | ADC084S101         |  |  |  |

(1) All devices are fully pin and function compatible.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



## **Connection Diagram**

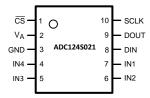
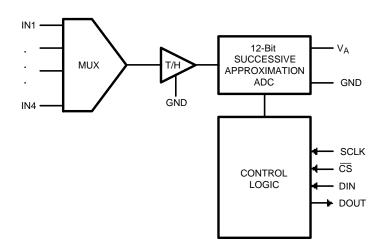


Figure 1. 10-Lead VSSOP See DGK Package

# **Block Diagram**



### PIN DESCRIPTIONS AND EQUIVALENT CIRCUITS

| Pin No.      | Symbol         | Description   |
|--------------|----------------|---|
| ANALOG I/O   |                |   |
| 4-7          | IN1 to IN4     | Analog inputs. These signals can range from 0V to V <sub>A</sub> .  |
| DIGITAL I/O  | •              |   |
| 10           | SCLK           | Digital clock input. This clock directly controls the conversion and readout processes.   |
| 9            | DOUT           | Digital data output. The output samples are clocked out of this pin on falling edges of the SCLK pin.   |
| 8            | DIN            | Digital data input. The ADC124S021's Control Register is loaded through this pin on rising edges of the SCLK pin.   |
| 1            | <del>CS</del>  | Chip select. On the falling edge of $\overline{\text{CS}}$ , a conversion process begins. Conversions continue as long as $\overline{\text{CS}}$ is held low.   |
| POWER SUPPLY |                |   |
| 2            | V <sub>A</sub> | Positive supply pin. This pin should be connected to a quiet +2.7V to +5.25V source and bypassed to GND with a 1 $\mu$ F capacitor and a 0.1 $\mu$ F monolithic capacitor located within 1 cm of the power pin. |
| 3            | GND            | The ground return for the supply and signals.   |

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# Absolute Maximum Ratings (1)(2)(3)

| Supply Voltage V <sub>A</sub>                                    | -0.3V to 6.5V                 |
|--|-------------------------------|
| Voltage on Any Pin to GND  | -0.3V to V <sub>A</sub> +0.3V |
| Input Current at Any Pin (4)                                     | ±10 mA                        |
| Package Input Current <sup>(4)</sup>                             | ±20 mA                        |
| Power Consumption at T <sub>A</sub> = 25°C                       | See (5)                       |
| ESD Susceptibility <sup>(6)</sup> Human Body Model Machine Model | 2500V<br>250V                 |
| Junction Temperature   | +150°C                        |
| Storage Temperature  | −65°C to +150°C               |

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not ensure specific performance limits. For ensured specifications and test conditions, see the Electrical Characteristics. The ensured specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.
- (2) All voltages are measured with respect to GND = 0V, unless otherwise specified.
- (3) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.
- (4) When the input voltage at any pin exceeds the power supply (that is, V<sub>IN</sub> < GND or V<sub>IN</sub> > V<sub>A</sub>), the current at that pin should be limited to 10 mA. The 20 mA maximum package input current rating limits the number of pins that can safely exceed the power supplies with an input current of 10 mA to two. The Absolute Maximum Rating specification does not apply to the V<sub>A</sub> pin. The current into the V<sub>A</sub> pin is limited by the Analog Supply Voltage specification.
- (5) The absolute maximum junction temperature (T<sub>J</sub>max) for this device is 150°C. The maximum allowable power dissipation is dictated by T<sub>J</sub>max, the junction-to-ambient thermal resistance (θ<sub>JA</sub>), and the ambient temperature (T<sub>A</sub>), and can be calculated using the formula P<sub>D</sub>MAX = (T<sub>J</sub>max T<sub>A</sub>)/θ<sub>JA</sub>. The values for maximum power dissipation listed above will be reached only when the device is operated in a severe fault condition (e.g. when input or output pins are driven beyond the power supply voltages, or the power supply polarity is reversed). Obviously, such conditions should always be avoided.
- (6) Human body model is 100 pF capacitor discharged through a 1.5 kΩ resistor. Machine model is 220 pF discharged through zero ohms.

### Operating Ratings (1)(2)

| Operating Natings                |                                |  |  |  |
|----------------------------------|--------------------------------|--|--|--|
| Operating Temperature Range      | -40°C ≤ T <sub>A</sub> ≤ +85°C |  |  |  |
| V <sub>A</sub> Supply Voltage    | +2.7V to +5.25V                |  |  |  |
| Digital Input Pins Voltage Range | -0.3V to V <sub>A</sub>        |  |  |  |
| Clock Frequency                  | 50 kHz to 16 MHz               |  |  |  |
| Analog Input Voltage             | 0V to V <sub>A</sub>           |  |  |  |

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not ensure specific performance limits. For ensured specifications and test conditions, see the Electrical Characteristics. The ensured specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.
- (2) All voltages are measured with respect to GND = 0V, unless otherwise specified.

### **Package Thermal Resistance**

| Package   | $\theta_{JA}$ |  |  |  |
|---|---------------|--|--|--|
| 10-lead VSSOP   | 190°C / W     |  |  |  |
| Soldering process must comply with Reflow Temperature Profile specifications. Refer to http://www.ti.com/packaging. (1) |               |  |  |  |

(1) Reflow temperature profiles are different for lead-free and non-lead-free packages.



# ADC124S021 Converter Electrical Characteristics (1)

The following specifications apply for  $V_A = +2.7V$  to 5.25V, GND = 0V,  $f_{SCLK} = 0.8$  MHz to 3.2 MHz,  $f_{SAMPLE} = 50$  ksps to 200 ksps,  $C_L = 35$  pF, unless otherwise noted. **Boldface limits apply for T\_A = T\_{MIN} to T\_{MAX}**: all other limits  $T_A = 25^{\circ}C$ .

| ONVERTER CHARACTERISTICS  Resolution with No Missing Codes  Integral Non-Linearity  Differential Non-Linearity  Offset Error  Channel to Channel Offset Error Match |  | +0.35<br>-0.35  | 12<br>+0.8   | Bits  |
|---|--|---|--|---|
| Integral Non-Linearity  Differential Non-Linearity  Offset Error  |  |   |  |   |
| Differential Non-Linearity Offset Error   |  |   | +0.8   |   |
| Differential Non-Linearity Offset Error   |  | -0.35   |  | LSB (max)   |
| Offset Error  |  |   | -1.1   | LSB (min)   |
| Offset Error  |  | +0.4  | +1.1   | LSB (max)   |
|   |  | -0.2  | -0.8   | LSB (min)   |
| Channel to Channel Offset Error Motch   |  | +0.37   | ±1.3   | LSB (max)   |
| Chamber to Chamber Offset Effor Match   |  | ±0.1  | ±1.0   | LSB (max)   |
| Full-Scale Error  |  | ±0.52   | ±1.5   | LSB (max)   |
| Channel to Channel Full-Scale Error<br>Match  |  | ±0.1  | ±1.0   | LSB (max)   |
| CONVERTER CHARACTERISTICS   |  |   |  |   |
| Signal-to-Noise Plus Distortion Ratio   | $V_A = +2.7 \text{ to } 5.25V$<br>$f_{IN} = 39.9 \text{ kHz}, -0.02 \text{ dBFS}$  | 72  | 69.2   | dB (min)  |
| Signal-to-Noise Ratio   | $V_A = +2.7 \text{ to } 5.25V$<br>$f_{IN} = 39.9 \text{ kHz}, -0.02 \text{ dBFS}$  | 72  | 70.6   | dB (min)  |
| Total Harmonic Distortion   | $V_A = +2.7 \text{ to } 5.25V$<br>$f_{IN} = 39.9 \text{ kHz}, -0.02 \text{ dBFS}$  | -84   | -75  | dB (max)  |
| Spurious-Free Dynamic Range   | $V_A = +2.7 \text{ to } 5.25 \text{V}$<br>$f_{IN} = 39.9 \text{ kHz}, -0.02 \text{ dBFS}$  | 86  | 76   | dB (min)  |
| Effective Number of Bits  | $V_A = +2.7 \text{ to } 5.25 \text{V}$   | 11.7  | 11.2   | Bits (min)  |
| Channel-to-Channel Crosstalk  | $V_A = +5.25V$<br>$f_{IN} = 39.9 \text{ kHz}$  | -86   |  | dB  |
| Intermodulation Distortion, Second Order Terms  | $V_A = +5.25V$<br>$f_a = 40.161 \text{ kHz}, f_b = 41.015 \text{ kHz}$   | -87   |  | dB  |
| Intermodulation Distortion, Third Order Terms   | $V_A = +5.25V$<br>$f_a = 40.161 \text{ kHz}, f_b = 41.015 \text{ kHz}$   | -88   |  | dB  |
| -3 dB Full Power Bandwidth  | V <sub>A</sub> = +5V   | 11  |  | MHz   |
| o db i dii i owei ballawatii  | V <sub>A</sub> = +3V   | 8   |  | MHz   |
| NPUT CHARACTERISTICS  |  | T   |  |   |
| Input Range   |  | 0 to V <sub>A</sub>   |  | V   |
| DC Leakage Current  |  | ±0.02   | ±1   | μA (max)  |
| Input Capacitance   | Track Mode   | 33  |  | pF  |
| · · ·   | Hold Mode  | 3   |  | pF  |
| NPUT CHARACTERISTICS  |  |   |  |   |
| Input High Voltage  |  |   |  | V (min)   |
| · · · · · · · · · · · · · · · · · · ·   | $V_A = +3.6V$  |   |  | V (min)   |
|   |  |   |  | V (max)   |
| •   | $V_{IN} = 0V \text{ or } V_A$  |   |  | μA (max)  |
| <u> </u>  |  | 2   | 4  | pF (max)  |
| DUTPUT CHARACTERISTICS  |  |   |  |   |
| Output High Voltage   | I <sub>SOURCE</sub> = 200 μA   |   | V <sub>A</sub> - 0.5   | V (min)   |
|   |  |   |  | V   |
| Output Low Voltage  | I <sub>SINK</sub> = 200 μA   | 0.02  | 0.4  | V (max)   |
|   | I <sub>SINK</sub> = 1 mA   | 0.1   |  | V<br>μΑ (max)   |
|   | Signal-to-Noise Ratio  Total Harmonic Distortion  Spurious-Free Dynamic Range  Effective Number of Bits  Channel-to-Channel Crosstalk  Intermodulation Distortion, Second Order Terms  Intermodulation Distortion, Third Order Terms  -3 dB Full Power Bandwidth  INPUT CHARACTERISTICS  Input Range | $ \begin{array}{c} \text{Signal-to-Noise Plus Distortion Ratio} & V_{A} = +2.7 \text{ to } 5.25 \text{V} \\ f_{\text{IN}} = 39.9 \text{ kHz}, -0.02 \text{ dBFS} \\ \hline \text{Signal-to-Noise Ratio} & V_{A} = +2.7 \text{ to } 5.25 \text{V} \\ f_{\text{IN}} = 39.9 \text{ kHz}, -0.02 \text{ dBFS} \\ \hline \text{VA} = +2.7 \text{ to } 5.25 \text{V} \\ f_{\text{IN}} = 39.9 \text{ kHz}, -0.02 \text{ dBFS} \\ \hline \text{VA} = +2.7 \text{ to } 5.25 \text{V} \\ f_{\text{IN}} = 39.9 \text{ kHz}, -0.02 \text{ dBFS} \\ \hline \text{Spurious-Free Dynamic Range} & V_{A} = +2.7 \text{ to } 5.25 \text{V} \\ f_{\text{IN}} = 39.9 \text{ kHz}, -0.02 \text{ dBFS} \\ \hline \text{Spurious-Free Dynamic Range} & V_{A} = +2.7 \text{ to } 5.25 \text{V} \\ f_{\text{IN}} = 39.9 \text{ kHz}, -0.02 \text{ dBFS} \\ \hline \text{Channel-to-Channel Crosstalk} & V_{A} = +5.25 \text{V} \\ f_{\text{IN}} = 39.9 \text{ kHz} \\ \hline \text{Intermodulation Distortion, Second} & V_{A} = +5.25 \text{V} \\ f_{a} = 40.161 \text{ kHz}, f_{b} = 41.015 \text{ kHz} \\ \hline \text{Order Terms} & V_{A} = +5.25 \text{V} \\ f_{a} = 40.161 \text{ kHz}, f_{b} = 41.015 \text{ kHz} \\ \hline \text{VA} = +3.2 \text{V} \\ \hline \text{VA} = +3 \text{V} \\ \hline \text{NPUT CHARACTERISTICS} \\ \hline \text{Input Range} & V_{A} = +5.2 \text{V} \\ \hline \text{Input Capacitance} & Track \text{ Mode} \\ \hline \text{Hold Mode} \\ \hline \text{NPUT CHARACTERISTICS} \\ \hline \text{Input High Voltage} & V_{A} = +5.25 \text{V} \\ \hline \text{VA} = +3.6 \text{V} \\ \hline \text{Input Low Voltage} \\ \hline \text{Input Current} & V_{\text{IN}} = 0 \text{V or V}_{A} \\ \hline \text{Digital Input Capacitance} \\ \hline \text{DUTPUT CHARACTERISTICS} \\ \hline \text{Output High Voltage} & \frac{I_{\text{SOURCE}} = 200  \mu\text{A}}{I_{\text{SOURCE}} = 1 \text{ mA}} \\ \hline \text{I}_{\text{SINK}} = 200  \mu\text{A} \\ \hline \text{I}_{\text{SINK}} = 200  \mu\text{A}} \\ \hline \text{I}_{\text{SINK}} = 1 \text{ mA} \\ \hline \end{array}$ | $\begin{array}{c} \text{Signal-to-Noise Plus Distortion Ratio} & \begin{cases} V_A = +2.7 \text{ to } 5.25 \text{V} \\ f_{\text{IN}} = 39.9 \text{ kHz}, -0.02 \text{ dBFS} \end{cases} & 72 \end{cases} \\ \text{Signal-to-Noise Ratio} & \begin{cases} V_A = +2.7 \text{ to } 5.25 \text{V} \\ f_{\text{IN}} = 39.9 \text{ kHz}, -0.02 \text{ dBFS}} \end{cases} & 72 \end{cases} \\ \text{Total Harmonic Distortion} & \begin{cases} V_A = +2.7 \text{ to } 5.25 \text{V} \\ f_{\text{IN}} = 39.9 \text{ kHz}, -0.02 \text{ dBFS}} \end{cases} & -84 \end{cases} \\ \text{Spurious-Free Dynamic Range} & \begin{cases} V_A = +2.7 \text{ to } 5.25 \text{V} \\ f_{\text{IN}} = 39.9 \text{ kHz}, -0.02 \text{ dBFS}} \end{cases} & 86 \end{cases} \\ \text{Spurious-Free Dynamic Range} & \begin{cases} V_A = +2.7 \text{ to } 5.25 \text{V} \\ f_{\text{IN}} = 39.9 \text{ kHz}, -0.02 \text{ dBFS}} \end{cases} & 86 \end{cases} \\ \text{Effective Number of Bits} & V_A = +2.7 \text{ to } 5.25 \text{V} \\ f_{\text{IN}} = 39.9 \text{ kHz}, -0.02 \text{ dBFS}} \end{cases} & 86 \end{cases} \\ \text{Effective Number of Bits} & V_A = +2.7 \text{ to } 5.25 \text{V} \\ f_{\text{IN}} = 39.9 \text{ kHz}, -0.02 \text{ dBFS}} \end{cases} & 86 \end{cases} \\ \text{Effective Number of Bits} & V_A = +2.7 \text{ to } 5.25 \text{V} \\ f_{\text{IN}} = 39.9 \text{ kHz}, -0.02 \text{ dBFS}} \end{cases} & 86 \end{cases} \\ \text{Effective Number of Bits} & V_A = +2.7 \text{ to } 5.25 \text{V} \\ f_{\text{IN}} = 39.9 \text{ kHz}, -0.02 \text{ dBFS}} \end{cases} & 86 \end{cases} \\ \text{Effective Number of Bits} & V_A = +2.7 \text{ to } 5.25 \text{V} \\ f_{\text{IN}} = 39.9 \text{ kHz}, -0.02 \text{ dBFS}} \end{cases} & 86 \end{cases} \\ \text{Effective Number of Bits} & V_A = +2.7 \text{ to } 5.25 \text{V} \\ f_{\text{IN}} = 39.9 \text{ kHz}, -0.02 \text{ dBFS}} \end{cases} & 86 \end{cases} \\ \text{Effective Number of Bits} & V_A = +2.7 \text{ to } 5.25 \text{V} \\ f_{\text{IN}} = 39.9 \text{ kHz}, -0.02 \text{ dBFS}} \end{cases} & 86 \end{cases} \\ \text{Effective Number of Bits} & V_A = +2.7 \text{ to } 5.25 \text{V} \\ f_{\text{IN}} = 39.9 \text{ kHz}, -0.02 \text{ dBFS}} \end{cases} & 86 \end{cases} \\ \text{Effective Number of Bits} & V_A = +5.25 \text{V} \\ f_{\text{IN}} = 40.161 \text{ kHz}, f_b = 41.015 \text{ kHz}} \end{cases} & -87 \end{cases} \\ English of Part of All of$ | Signal-to-Noise Plus Distortion Ratio   V <sub>A</sub> = +2.7 to 5.25V   f <sub>IN</sub> = 39.9 kHz, -0.02 dBFS   72   70.6     Signal-to-Noise Ratio   V <sub>A</sub> = +2.7 to 5.25V   72   70.6     Total Harmonic Distortion   V <sub>A</sub> = +2.7 to 5.25V   72   70.6     Total Harmonic Distortion   V <sub>A</sub> = +2.7 to 5.25V   -84   -75     Spurious-Free Dynamic Range   V <sub>A</sub> = +2.7 to 5.25V   86   76     Spurious-Free Dynamic Range   V <sub>A</sub> = +2.7 to 5.25V   86   76     Effective Number of Bits   V <sub>A</sub> = +2.7 to 5.25V   11.7   11.2     Channel-to-Channel Crosstalk   V <sub>A</sub> = +2.7 to 5.25V   11.7   11.2     Channel-to-Channel Crosstalk   V <sub>A</sub> = +5.25V   -86   Intermodulation Distortion, Second   V <sub>A</sub> = +5.25V   -86   Intermodulation Distortion, Third Order   V <sub>A</sub> = +5.25V   -87   -87     Intermodulation Distortion, Third Order   V <sub>A</sub> = +5.25V   -88   -88   -88     -3 dB Full Power Bandwidth   V <sub>A</sub> = +5.25V   11   -88   -88     -3 dB Full Power Bandwidth   V <sub>A</sub> = +3.0V   8   11   -98     INPUT CHARACTERISTICS   Input Range   0 to V <sub>A</sub>   -88     Input Capacitance   Track Mode   3   3   -98   -98   -98     Input Characteristics   V <sub>A</sub> = +3.6V   2.4   -98 |

Product Folder Links: ADC124S021

<sup>(1)</sup> Min/max specification limits are ensured by design, test, or statistical analysis.

<sup>(2)</sup> Tested limits are specified to TI's AOQL (Average Outgoing Quality Level).



# ADC124S021 Converter Electrical Characteristics (1) (continued)

The following specifications apply for  $V_A$  = +2.7V to 5.25V, GND = 0V,  $f_{SCLK}$  = 0.8 MHz to 3.2 MHz,  $f_{SAMPLE}$  = 50 ksps to 200 ksps,  $C_L$  = 35 pF, unless otherwise noted. **Boldface limits apply for T\_A = T\_{MIN} to T\_{MAX}**: all other limits  $T_A$  = 25°C.

| Symbol                             | Parameter                                     | Conditions   | Typical | Limits (2)       | Units       |
|------------------------------------|---|--|---------|------------------|-------------|
| C <sub>OUT</sub>                   | TRI-STATE® Output Capacitance                 |  | 2       | 4                | pF (max)    |
| Output Coding                      |   |  | St      | raight (Natural) | ) Binary    |
| POWER S                            | SUPPLY CHARACTERISTICS ( $C_L = 10 \text{ p}$ | pF)  |         |                  |             |
| \/                                 | Supply Voltage                                |  |         | 2.7              | V (min)     |
| V <sub>A</sub> S                   | Supply Voltage                                |  |         | 5.25             | V (max)     |
|                                    | Supply Current, Normal Mode                   | $V_A = +5.25V$<br>$f_{SAMPLE} = 200 \text{ ksps}, f_{IN} = 39.9 \text{ kHz}$     | 1.5     | 2.1              | mA (max)    |
| ı.                                 | (Operational, CS low)                         | $V_A = +3.6V$ ,<br>$f_{SAMPLE} = 200 \text{ ksps}$ , $f_{IN} = 39.9 \text{ kHz}$ | 0.62    | 1.0              | mA (max)    |
| A                                  | $V_A = +5.25V$<br>$f_{SAMPLE} = 0$ ksps       | 60   |         | nA               |             |
| Supply Current, Shutdown (CS high) |   | $V_A = +3.6V$ ,<br>$f_{SAMPLE} = 0$ ksps   | 38      |                  | nA          |
|                                    | Power Consumption, Normal Mode                | $V_A = +5.25V$   | 7.9     | 11.0             | mW (max)    |
| D                                  | (Operational, CS low)                         | $V_A = +3.6V$ ,  | 2.2     | 3.6              | mW (max)    |
| $P_D$                              | Power Consumption, Shutdown (CS               | $V_A = +5.25V$   | 0.32    |                  | μW          |
| high)                              |   | $V_A = +3.6V$ ,  | 0.14    |                  | μW          |
| AC ELEC                            | TRICAL CHARACTERISTICS                        |  |         |                  |             |
| ( Mariana Olas I Francisco         |   | Clock Frequency (3)  |         | 0.8              | MHz (min)   |
| f <sub>SCLK</sub>                  | Maximum Clock Frequency                       |  |         | 3.2              | MHz (max)   |
| ı                                  | Comple Date                                   | (3)  |         | 50               | ksps (min)  |
| f <sub>S</sub>                     | Sample Rate                                   | (5)  |         | 200              | ksps (max)  |
| t <sub>CONV</sub>                  | Conversion Time                               |  |         | 13               | SCLK cycles |
| DC                                 | SCL K Durty Cycle                             | f 2.2 MH=  | 50      | 30               | % (min)     |
| DC                                 | SCLK Duty Cycle                               | f <sub>SCLK</sub> = 3.2 MHz  | 50      | 70               | % (max)     |
| t <sub>ACQ</sub>                   | Track/Hold Acquisition Time                   | Full-Scale Step Input  |         | 3                | SCLK cycles |
|                                    | Throughput Time                               | Acquisition Time + Conversion Time   |         | 16               | SCLK cycles |

<sup>(3)</sup> This is the frequency range over which the electrical performance is ensured. The device is functional over a wider range which is specified under Operating Ratings.

# **ADC124S021 Timing Specifications**

The following specifications apply for  $V_A$  = +2.7V to 5.25V, GND = 0V,  $f_{SCLK}$  = 0.8 MHz to 3.2 MHz,  $f_{SAMPLE}$  = 50 ksps to 200 ksps,  $C_L$  = 35 pF, **Boldface limits apply for T\_A = T\_{MIN} to T\_{MAX}**: all other limits  $T_A$  = 25°C.

| Symbol   | Parameter                                 |  | Conditions    | Typical                 | Limits (1)              | Units        |
|--|---|--|---------------|-------------------------|-------------------------|--------------|
| t <sub>CSI</sub> Setup Time SCLK High to $\overline{\text{CS}}$ Falling Edge |   | atun Time SCLK High to CS Falling Edge (2) |               | -3.5                    | 10                      | ns (min)     |
| t <sub>CSU</sub>   | Setup Time SCLK High to CS Falling Edge   |  | $V_A = +5.0V$ | -0.5                    | 10                      | 115 (111111) |
| 4  | Hald the COURT and to CO Falling Edge     |  | $V_A = +3.0V$ | +4.5                    | 10                      | no (min)     |
| t <sub>CLH</sub>   | old time SCLK Low to CS Falling Edge      | (2)  | $V_A = +5.0V$ | +1.5                    | 10                      | ns (min)     |
|  | Delay from CS Until DOUT active           |  | $V_A = +3.0V$ | +4                      | 20 (                    |              |
| t <sub>EN</sub>  | Delay IIOIII C3 OIIIII DOOT active        |  | $V_A = +5.0V$ | +2                      | 30                      | ns (max)     |
| +  | Data Access Time after SCLK Falling Edge  |  | $V_A = +3.0V$ | +14.5                   | 30                      | ns (max)     |
| t <sub>ACC</sub>   | Data Access Time after SCLK Failing Edge  |  | $V_A = +5.0V$ | +13                     | 30                      | ns (max)     |
| t <sub>SU</sub>  | Data Setup Time Prior to SCLK Rising Edge |  |               | +3                      | 10                      | ns (min)     |
| t <sub>H</sub>   | Data Valid SCLK Hold Time                 |  |               | +3                      | 10                      | ns (min)     |
| t <sub>CH</sub>  | SCLK High Pulse Width                     |  |               | 0.5 x t <sub>SCLK</sub> | 0.3 x t <sub>SCLK</sub> | ns (min)     |

<sup>(1)</sup> Tested limits are specified to TI's AOQL (Average Outgoing Quality Level).

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<sup>(2)</sup> Clock may be either high or low when CS is asserted as long as setup and hold times t<sub>CSU</sub> and t<sub>CLH</sub> are strictly observed.



## **ADC124S021 Timing Specifications (continued)**

The following specifications apply for  $V_A$  = +2.7V to 5.25V, GND = 0V,  $f_{SCLK}$  = 0.8 MHz to 3.2 MHz,  $f_{SAMPLE}$  = 50 ksps to 200 ksps,  $C_L$  = 35 pF, **Boldface limits apply for T\_A = T\_{MIN} to T\_{MAX}**: all other limits  $T_A$  = 25°C.

| Symbol           | Parameter                             | Conditions     |               | Typical                 | Limits (1)              | Units    |
|------------------|---------------------------------------|----------------|---------------|-------------------------|-------------------------|----------|
| t <sub>CL</sub>  | SCLK Low Pulse Width                  |                |               | 0.5 x t <sub>SCLK</sub> | 0.3 x t <sub>SCLK</sub> | ns (min) |
|                  |                                       |                | $V_A = +3.0V$ | 1.8                     |                         |          |
| t <sub>DIS</sub> | CS Rising Edge to DOUT High-Impedance | Output Falling | $V_A = +5.0V$ | 1.3                     | 20                      | no (mov) |
|                  |                                       | Outrat Disian  | $V_A = +3.0V$ | 1.0                     |                         | ns (max) |
|                  |                                       | Output Rising  | $V_A = +5.0V$ | 1.0                     |                         |          |

## **Timing Diagrams**

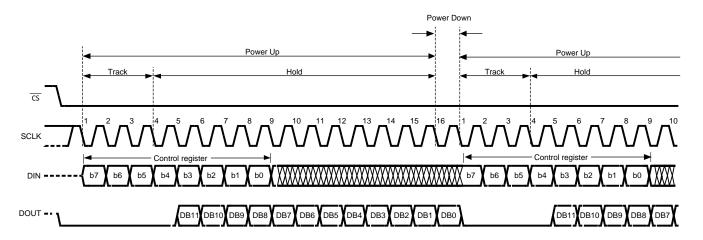


Figure 2. ADC124S021 Operational Timing Diagram

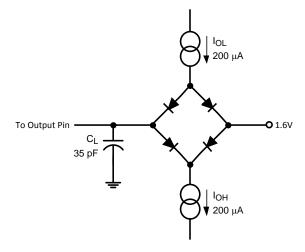


Figure 3. Timing Test Circuit



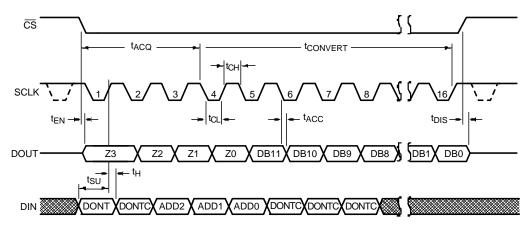


Figure 4. ADC124S021 Serial Timing Diagram

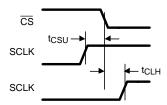


Figure 5. SCLK and CS Timing Parameters

### **Specification Definitions**

- **ACQUISITION TIME** is the time required to acquire the input voltage. That is, it is time required for the hold capacitor to charge up to the input voltage.
- **APERTURE DELAY** is the time between the fourth falling SCLK edge of a conversion and the time when the input signal is acquired or held for conversion.
- **CONVERSION TIME** is the time required, after the input voltage is acquired, for the ADC to convert the input voltage to a digital word.
- **CROSSTALK** is the coupling of energy from one channel into the other channel, or the amount of signal energy from one analog input that appears at the measured analog input.
- **DIFFERENTIAL NON-LINEARITY (DNL)** is the measure of the maximum deviation from the ideal step size of 1 LSB.
- **DUTY CYCLE** is the ratio of the time that a repetitive digital waveform is high to the total time of one period. The specification here refers to the SCLK
- **EFFECTIVE NUMBER OF BITS (ENOB, or EFFECTIVE BITS)** is another method of specifying Signal-to-Noise and Distortion or SINAD. ENOB is defined as (SINAD 1.76) / 6.02 and says that the converter is equivalent to a perfect ADC of this (ENOB) number of bits.
- **FULL POWER BANDWIDTH** is a measure of the frequency at which the reconstructed output fundamental drops 3 dB below its low frequency value for a full scale input.
- **FULL SCALE ERROR (FSE)** is a measure of how far the last code transition is from the ideal 1½ LSB below  $V_{REF}^+$  and is defined as:

$$V_{FSE} = V_{max} + 1.5 LSB - V_{REF}^{+}$$

### where

- V<sub>max</sub> is the voltage at which the transition to the maximum code occurs
- FSE can be expressed in Volts, LSB or percent of full scale range

(1)

(2)



- **GAIN ERROR** is the deviation of the last code transition (111...110) to (111...111) from the ideal (V<sub>REF</sub> 1.5 LSB), after adjusting for offset error.
- INTEGRAL NON-LINEARITY (INL) is a measure of the deviation of each individual code from a line drawn from negative full scale (½ LSB below the first code transition) through positive full scale (½ LSB above the last code transition). The deviation of any given code from this straight line is measured from the center of that code value.
- **INTERMODULATION DISTORTION (IMD)** is the creation of additional spectral components as a result of two sinusoidal frequencies being applied to the ADC input at the same time. It is defined as the ratio of the power in the second and third order intermodulation products to the power in one of the original frequencies. IMD is usually expressed in dB.
- **MISSING CODES** are those output codes that will never appear at the ADC outputs. These codes cannot be reached with any input value. The ADC124S021 is ensured not to have any missing codes.
- **OFFSET ERROR** is the deviation of the first code transition (000...000) to (000...001) from the ideal (i.e. GND + 0.5 LSB).
- **SIGNAL TO NOISE RATIO (SNR)** is the ratio, expressed in dB, of the rms value of the input signal to the rms value of the sum of all other spectral components below one-half the sampling frequency, not including d.c. or the harmonics included in THD.
- **SIGNAL TO NOISE PLUS DISTORTION (S/N+D or SINAD)** Is the ratio, expressed in dB, of the rms value of the input signal to the rms value of all of the other spectral components below half the clock frequency, including harmonics but excluding d.c.
- **SPURIOUS FREE DYNAMIC RANGE (SFDR)** is the difference, expressed in dB, between the desired signal amplitude to the amplitude of the peak spurious spectral component, where a spurious spectral component is any signal present in the output spectrum that is not present at the input and may or may not be a harmonic.
- **TOTAL HARMONIC DISTORTION (THD)** is the ratio, expressed in dB or dBc, of the rms total of the first five harmonic components at the output to the rms level of the input signal frequency as seen at the output. THD is calculated as

THD = 
$$20 \cdot \log_{10} \sqrt{\frac{A_{f2}^2 + \dots + A_{f6}^2}{A_{f1}^2}}$$

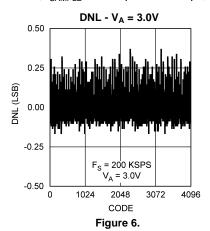
#### where

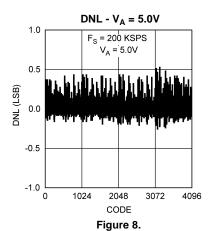
- Af<sub>1</sub> is the RMS power of the input frequency at the output
- Af<sub>2</sub> through Af<sub>6</sub> are the RMS power in the first 5 harmonic frequencies

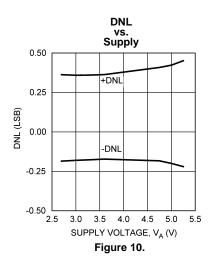
**THROUGHPUT TIME** is the minimum time required between the start of two successive conversion. It is the acquisition time plus the conversion and read out times. In the case of the ADC124S021, this is 16 SCLK periods.

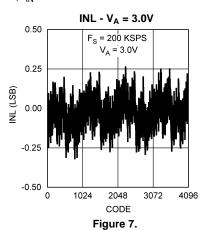


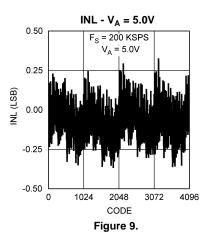
### **Typical Performance Characteristics**

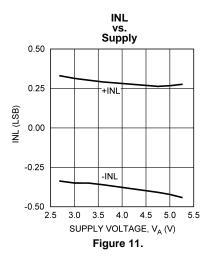






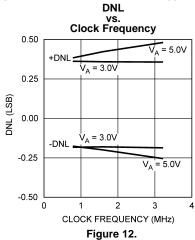








 $T_A$  = +25°C,  $f_{SAMPLE}$  = 50 ksps to 200 ksps,  $f_{SCLK}$  = 0.8 MHz to 3.2 MHz,  $f_{IN}$  = 39.9 kHz unless otherwise stated.





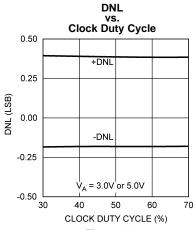
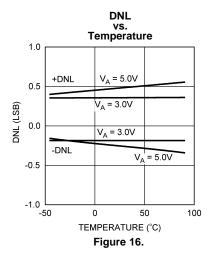


Figure 14.



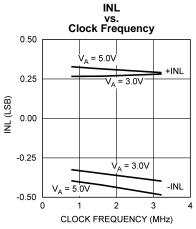


Figure 13.

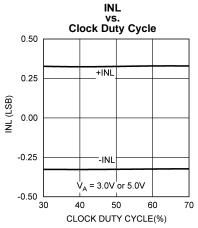
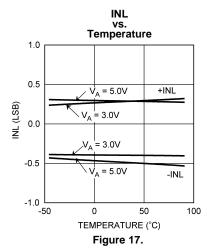
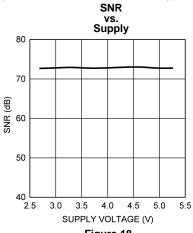


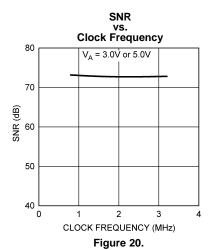
Figure 15.

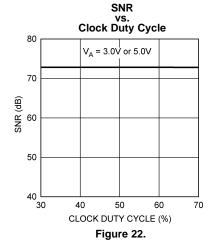












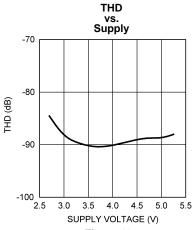


Figure 19.

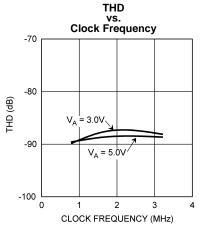
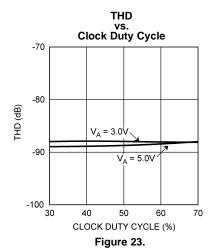


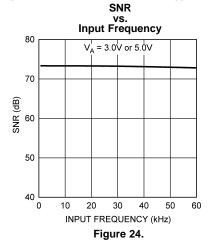
Figure 21.

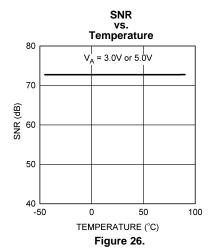


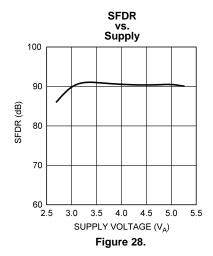
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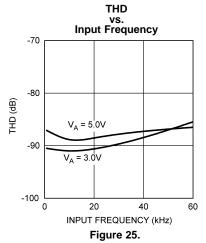
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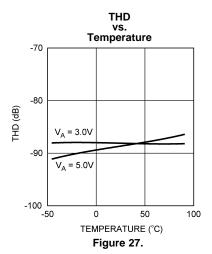


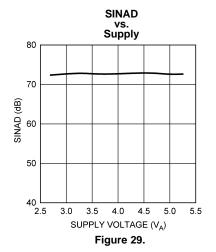




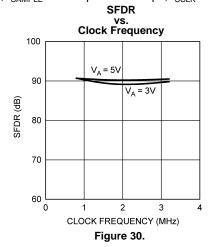


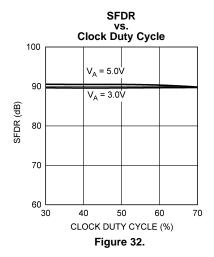


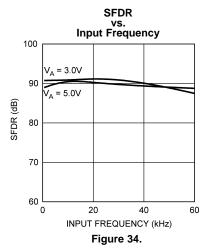


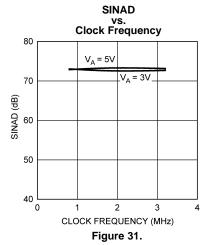


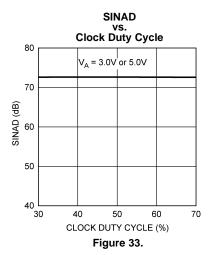


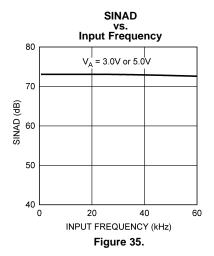






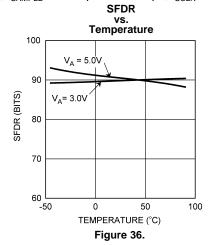


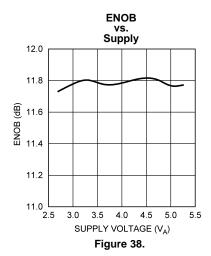


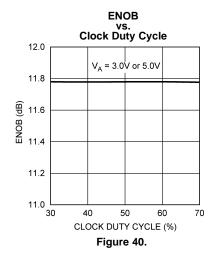


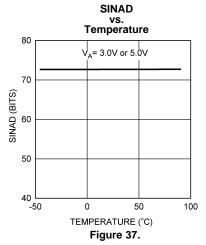


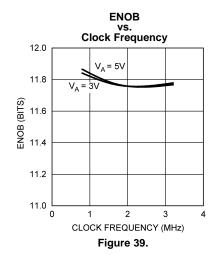
 $T_A$  = +25°C,  $f_{SAMPLE}$  = 50 ksps to 200 ksps,  $f_{SCLK}$  = 0.8 MHz to 3.2 MHz,  $f_{IN}$  = 39.9 kHz unless otherwise stated.

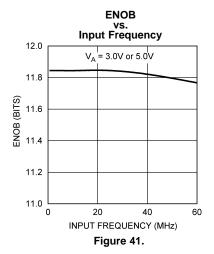




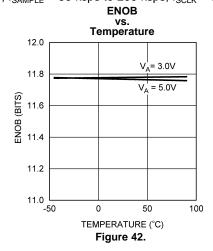


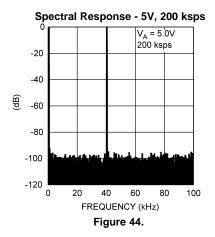


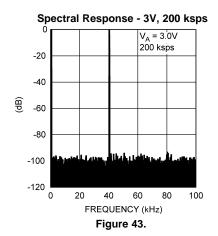


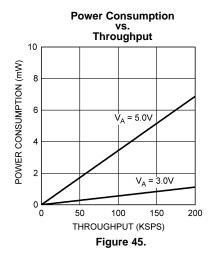














#### APPLICATIONS INFORMATION

#### 1.0 ADC124S021 OPERATION

The ADC124S021 is a successive-approximation analog-to-digital converter designed around a charge-redistribution digital-to-analog converter. Simplified schematics of the ADC124S021 in both track and hold modes are shown in Figure 46, and Figure 47, respectively. In Figure 46, the ADC124S021 is in track mode: switch SW1 connects the sampling capacitor to one of four analog input channels through the multiplexer, and SW2 balances the comparator inputs. The ADC124S021 is in this state for the first three SCLK cycles after  $\overline{\text{CS}}$  is brought low.

Figure 47 shows the ADC124S021 in hold mode: switch SW1 connects the sampling capacitor to ground, maintaining the sampled voltage, and switch SW2 unbalances the comparator. The control logic then instructs the charge-redistribution DAC to add fixed amounts of charge to the sampling capacitor until the comparator is balanced. When the comparator is balanced, the digital word supplied to the DAC is the digital representation of the analog input voltage. The ADC124S021 is in this state for the fourth through sixteenth SCLK cycles after  $\overline{\text{CS}}$  is brought low.

The time when  $\overline{\text{CS}}$  is low is considered a serial frame. Each of these frames should contain an integer multiple of 16 SCLK cycles, during which time a conversion is performed and clocked out at the DOUT pin and data is clocked into the DIN pin to indicate the multiplexer address for the next conversion.

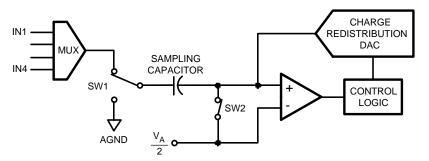


Figure 46. ADC124S021 in Track Mode

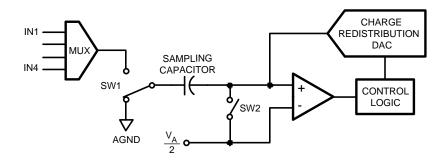


Figure 47. ADC124S021 in Hold Mode

#### 2.0 USING THE ADC124S021

Figure 2 and Figure 4 for the ADC124S021 are shown in Timing Diagrams.  $\overline{CS}$  is chip select, which initiates conversions and frames the serial data transfers. SCLK (serial clock) controls both the conversion process and the timing of serial data. DOUT is the serial data output pin, where a conversion result is sent as a serial data stream, MSB first. Data to be written to the ADC124S021's Control Register is placed on DIN, the serial data input pin. New data is written to the ADC at DIN with each conversion.

A serial frame is initiated on the falling edge of  $\overline{CS}$  and ends on the rising edge of  $\overline{CS}$ . Each frame must contain an integer multiple of 16 rising SCLK edges. The ADC output data (DOUT) is in a high impedance state when  $\overline{CS}$  is high and is active when  $\overline{CS}$  is low. Thus,  $\overline{CS}$  acts as an output enable. Additionally, the device goes into a power down state when  $\overline{CS}$  is high, and also between continuous conversion cycles.



During the first 3 cycles of SCLK, the ADC is in the track mode, acquiring the input voltage. For the next 13 SCLK cycles the conversion is accomplished and the data is clocked out, MSB first, starting on the 5th clock. If there is more than one conversion in a frame, the ADC will re-enter the track mode on the falling edge of SCLK after the N\*16th rising edge of SCLK, and re-enter the hold/convert mode on the N\*16+4th falling edge of SCLK, where "N" is an integer.

When  $\overline{CS}$  is brought high, SCLK is internally gated off. If SCLK is stopped in the low state while  $\overline{CS}$  is high, the subsequent fall of  $\overline{CS}$  will generate a falling edge of the internal version of SCLK, putting the ADC into the track mode. This is seen by the ADC as the first falling edge of SCLK. If SCLK is stopped with SCLK high, the ADC enters the track mode on the first falling edge of SCLK after the falling edge of  $\overline{CS}$ .

During each conversion, data is clocked into the DIN pin on the first 8 rising edges of SCLK after the fall of  $\overline{CS}$ . For each conversion, it is necessary to clock in the data indicating the input that is selected for the conversion after the current one. See Table 2, Table 3, and Table 4.

If  $\overline{\text{CS}}$  and SCLK go low within the times defined by  $t_{\text{CSU}}$  and  $t_{\text{CLH}}$ , the rising edge of SCLK that begins clocking data in at DIN may be one clock cycle later than expected. It is, therefore, best to strictly observe the minimum  $t_{\text{CSU}}$  and  $t_{\text{CLH}}$  times given in ADC124S021 Timing Specifications .

There are no power-up delays or dummy conversions required with the ADC124S021. The ADC is able to sample and convert an input to full conversion immediately following power up. The first conversion result after power-up will be that of IN1.

#### **Table 2. Control Register Bits**

| Bit 7 (MSB) | Bit 6 | Bit 5 | Bit 4 | Bit 3 | Bit 2 | Bit 1 | Bit 0 |
|-------------|-------|-------|-------|-------|-------|-------|-------|
| DONTC       | DONTC | ADD2  | ADD1  | ADD0  | DONTC | DONTC | DONTC |

### **Table 3. Control Register Bit Descriptions**

| Bit #:       | Symbol: | Description  |
|--------------|---------|--|
| 7 - 6, 2 - 0 | DONTC   | Don't care. The value of these bits do not affect device operation.                      |
| 5            | ADD2    | These three bits determine which input channel will be sampled and converted in the next |
| 4            | ADD1    | track/hold cycle. The mapping between codes and channels is shown in Table 4.            |
| 3            | ADD0    |  |

### **Table 4. Input Channel Selection**

| ADD2 | ADD1 | ADD0 | Input Channel |
|------|------|------|---------------|
| Х    | 0    | 0    | IN1 (Default) |
| Х    | 0    | 1    | IN2           |
| Х    | 1    | 0    | IN3           |
| X    | 1    | 1    | IN4           |

### 3.0 ADC124S021 TRANSFER FUNCTION

The output format of the ADC124S021 is straight binary. Code transitions occur midway between successive integer LSB values. The LSB width for the ADC124S021 is  $V_A/4096$ . The ideal transfer characteristic is shown in Figure 3. The transition from an output code of 0000 0000 0000 to a code of 0000 0000 0001 is at 1/2 LSB, or a voltage of  $V_A/8192$ . Other code transitions occur at steps of one LSB.



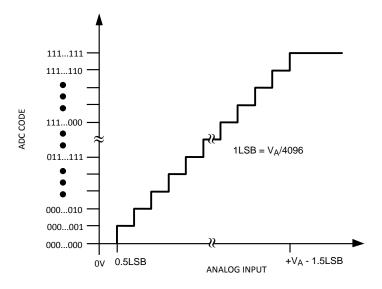


Figure 48. Ideal Transfer Characteristic

### 4.0 TYPICAL APPLICATION CIRCUIT

A typical application of the ADC124S021 is shown in Figure 49. Power is provided in this example by the Texas Instruments LP2950 low-dropout voltage regulator, available in a variety of fixed and adjustable output voltages. The power supply pin is bypassed with a capacitor network located close to the ADC124S021.

Because the reference for the ADC124S021 is the supply voltage, any noise on the supply will degrade device noise performance. To keep noise off the supply, use a dedicated linear regulator for this device, or provide sufficient decoupling from other circuitry to keep noise off the ADC124S021 supply pin. Because of the ADC124S021's low power requirements, it is also possible to use a precision reference as a power supply to maximize performance. The four-wire interface is also shown connected to a microprocessor or DSP.

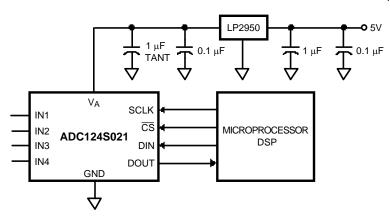


Figure 49. Typical Application Circuit

### 5.0 ANALOG INPUTS

An equivalent circuit for one of the ADC124S021's input channels is shown in Figure 5. Diodes D1 and D2 provide ESD protection for the analog inputs. At no time should any input go beyond ( $V_A$  + 300 mV) or (GND – 300 mV), as these ESD diodes will begin conducting, which could result in erratic operation. For this reason, these ESD diodes should NOT be used to clamp the input signal.



The capacitor C1 in Figure 5 has a typical value of 3 pF, and is mainly the package pin capacitance. Resistor R1 is the on resistance of the multiplexer and track / hold switch, and is typically 500 ohms. Capacitor C2 is the ADC124S021 sampling capacitor, and is typically 30 pF. The ADC124S021 will deliver best performance when driven by a low-impedance source to eliminate distortion caused by the charging of the sampling capacitance. This is especially important when using the ADC124S021 to sample AC signals. Also important when sampling dynamic signals is a band-pass or low-pass filter to reduce harmonics and noise, improving dynamic performance.

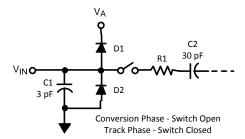


Figure 50. Equivalent Input Circuit

#### 6.0 DIGITAL INPUTS AND OUTPUTS

The ADC124S021's digital output DOUT is limited by, and cannot exceed, the supply voltage,  $V_A$ . The digital input pins are not prone to latch-up and, and although not recommended, SCLK, CS and DIN may be asserted before  $V_A$  without any latch-up risk.

### 7.0 POWER SUPPLY CONSIDERATIONS

The ADC124S021 is fully powered-up whenever  $\overline{CS}$  is low, and fully powered-down whenever  $\overline{CS}$  is high, with one exception: the ADC124S021 automatically enters power-down mode between the 16th falling edge of a conversion and the 1st falling edge of the subsequent conversion (see Timing Diagramss).

The ADC124S021 can perform multiple conversions back to back; each conversion requires 16 SCLK cycles. The ADC124S021 will perform conversions continuously as long as CS is held low.

The user may trade off throughput for power consumption by simply performing fewer conversions per unit time. Figure 45 in Typical Performance Characteristics shows the typical power consumption of the ADC124S021 versus throughput. To calculate the power consumption, simply multiply the fraction of time spent in the normal mode by the normal mode power consumption , and add the fraction of time spent in shutdown mode multiplied by the shutdown mode power dissipation.

### 7.1 Power Management

When the ADC124S021 is operated continuously in normal mode, the maximum throughput is  $f_{SCLK}/16$ . Throughput may be traded for power consumption by running  $f_{SCLK}$  at its maximum 3.2 MHz and performing fewer conversions per unit time, putting the ADC124S021 into shutdown mode between conversions. Figure 45 is shown in Typical Performance Characteristics. To calculate the power consumption for a given throughput, multiply the fraction of time spent in the normal mode by the normal mode power consumption and add the fraction of time spent in shutdown mode multiplied by the shutdown mode power consumption. Generally, the user will put the part into normal mode and then put the part back into shutdown mode. Note that Figure 45 is nearly linear. This is because the power consumption in the shutdown mode is so small that it can be ignored for all practical purposes.



### 7.2 Power Supply Noise Considerations

The charging of any output load capacitance requires current from the power supply,  $V_A$ . The current pulses required from the supply to charge the output capacitance will cause voltage variations on the supply. If these variations are large enough, they could degrade SNR and SINAD performance of the ADC. Furthermore, discharging the output capacitance when the digital output goes from a logic high to a logic low will dump current into the die substrate, which is resistive. Load discharge currents will cause "ground bounce" noise in the substrate that will degrade noise performance if that current is large enough. The larger is the output capacitance, the more current flows through the die substrate and the greater is the noise coupled into the analog channel, degrading noise performance.

To keep noise out of the power supply, keep the output load capacitance as small as practical. If the load capacitance is greater than 35 pF, use a 100  $\Omega$  series resistor at the ADC output, located as close to the ADC output pin as practical. This will limit the charge and discharge current of the output capacitance and improve noise performance.





## **REVISION HISTORY**

| Cł | nanges from Revision E (March 2013) to Revision F  | Page |
|----|--|------|
| •  | Changed layout of National Data Sheet to TI format | 20   |



## PACKAGE OPTION ADDENDUM

25-Feb-2015

#### PACKAGING INFORMATION

| Orderable Device     | Status | Package Type | Package<br>Drawing | Pins | _    |                            | Lead/Ball Finish | MSL Peak Temp      | Op Temp (°C) | Device Marking | Samples |
|----------------------|--------|--------------|--------------------|------|------|----------------------------|------------------|--------------------|--------------|----------------|---------|
|                      | (1)    |              | Diawing            |      | Qty  | (2)                        | (6)              | (3)                |              | (4/5)          |         |
| ADC124S021CIMM/NOPB  | ACTIVE | VSSOP        | DGS                | 10   | 1000 | Green (RoHS<br>& no Sb/Br) | CU SN            | Level-1-260C-UNLIM | -40 to 85    | X21C           | Samples |
| ADC124S021CIMMX/NOPB | ACTIVE | VSSOP        | DGS                | 10   | 3500 | Green (RoHS<br>& no Sb/Br) | CU SN            | Level-1-260C-UNLIM | -40 to 85    | X21C           | Samples |

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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# **PACKAGE OPTION ADDENDUM**

25-Feb-2015

| n no event shall TI's liability arising out of | such information exceed the total purchase pr | rice of the TI part(s) at issue in this | document sold by TI to Customer on an annual basis. |
|--|---|---|---|
|  |   |   |   |

# **PACKAGE MATERIALS INFORMATION**

www.ti.com 5-Dec-2014

# TAPE AND REEL INFORMATION





|    | Dimension designed to accommodate the component width     |
|----|---|
|    | Dimension designed to accommodate the component length    |
| K0 | Dimension designed to accommodate the component thickness |
| W  | Overall width of the carrier tape                         |
| P1 | Pitch between successive cavity centers                   |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



### \*All dimensions are nominal

| Device                   | Package<br>Type | Package<br>Drawing |    | SPQ  | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
|--------------------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| ADC124S021CIMM/NOPB      | VSSOP           | DGS                | 10 | 1000 | 178.0                    | 12.4                     | 5.3        | 3.4        | 1.4        | 8.0        | 12.0      | Q1               |
| ADC124S021CIMMX/NOP<br>B | VSSOP           | DGS                | 10 | 3500 | 330.0                    | 12.4                     | 5.3        | 3.4        | 1.4        | 8.0        | 12.0      | Q1               |

www.ti.com 5-Dec-2014



#### \*All dimensions are nominal

| Device                   | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|--------------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| ADC124S021CIMM/NOPB      | VSSOP        | DGS             | 10   | 1000 | 210.0       | 185.0      | 35.0        |
| ADC124S021CIMMX/NOP<br>B | VSSOP        | DGS             | 10   | 3500 | 367.0       | 367.0      | 35.0        |



SMALL OUTLINE PACKAGE



### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187, variation BA.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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